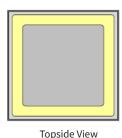


Gen 6 Silicon Carbide Schottky Diode

Description

This is the 6th generation of high voltage, high performace Z-Rec[©] silicon carbide Schottky diode in a packageless bare die format to be implemented into any custom module design. The lower forward voltage, smaller reverse leakage current, zero reverse recovery, and high thermal conductivity make this schottky diode ideal for high frequency switching applications including high density DC to DC converters. This schottky diode can be used in conjunction with either IGBT or MOSFET as an anti-parallel diode, or as a rectifier.





(Anode)

Package Type: Bare Die PN: CPW6-1700-Z005A

Features

- 1700V Schottky Rectifier
- Zero Reverse Recovery
- Zero Forward Recovery
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_E

Applications

- Solar Inverters
- Motor Drives
- EV Chargers
- UPS
- Industrial Power Supplies

Absolute Maximum Ratings (T_j = 25 °C unless otherwise specified)

Stress beyond those listed under absolute maximum ratings may damage the device

Parameter	Symbol	Rating	Unit	Comments
Repetitive Peak Reverse Voltage	V _{RRM}	1700	V	
Continuous Forward Current		21	Α	T _c = 25°C
	I _F	12	Α	T _c = 125°C
		8	Α	T _c = 150°C
Repetitive Peak Forward Surge Current		33	Α	$T_c = 25$ °C, $t_p = 10$ ms, Half Sine Pulse
	FRM	19	Α	T _c = 110°C, t _p = 10ms, Half Sine Pulse
Non-repetitive Forward Surge Current		87	Α	T _c = 25°C, t _p = 10ms, Half Sine Pulse
	FSM	73	Α	T _c = 110°C, t _p = 10ms, Half Sine Pulse
Operating Junction and Storage Temperature	$T_{v_{j}},T_{stg}$	-55 to +175	°C	
Processing Temperature	T _{proc}	325	°C	Non-reactive ambient

Note -All above notation to T $_c$ specifies case temperature from die packaged in TO-247, with $R_{th(i-c)} < 1.36$ °C/W

Electrical Characteristics

Parameter	Symbol	Typical	Max	Unit	Test Conditions
Forward Voltage	V _F	1.5		V	$I_F = 5A, T_{v_j} = 25^{\circ}C$
		1.9			$I_F = 5A, T_{vj} = 175^{\circ}C$
Reverse Current	I _R	0.42		μΑ	$V_R = 1700V, T_{vj} = 25^{\circ}C$
		4.18			V _R = 1700V, T _{vj} = 175°C
Total Capacitive Charge	Q _c	79		nC	V _R = 1700V, T _{vj} = 25°C
Total Capacitance	С	639		pF	$V_R = 0V$, $T_{vj} = 25$ °C, $f = 1$ MHz
		35			$V_R = 800V, T_{v_j} = 25^{\circ}C, f = 1MHz$
		34			V _R = 1700V, T _{vj} = 25°C, f = 1MHz
Capacitance Stored Energy	E _c	52		μJ	V _R = 1700V

Note:

All 175°C values are guaranteed by design and characterization

Thermal Characteristics

Parameter	Symbol	Typical	Unit
Thermal Resistance from Junctin to Case ¹	$R_{th(j-c)}$	0.95	°C/W

Note:

Mechanical Parameters

Parameter	Typical	Units
Die Size	2.25 x 2.25	mm
Anode Pad Opening	1.35 x 1.35	mm
Die Thickness	360	μm
Topside Anode Metalization (Al)	4	μm
Backside Cathode Metalization (Ni)	0.8	μm
Backside Cathode Metalization (Au)	0.01	μm
Frontside Passivation (polymide)	7.3	μm

¹Tested in TO-247 package

3

Typical Performance

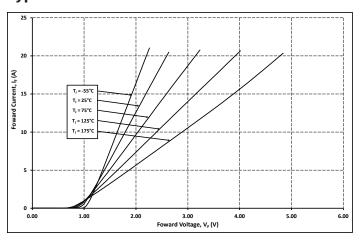


Figure 1Typical Forward Characteristics

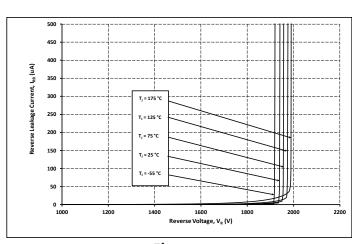


Figure 2Typical Reverse Characteristics

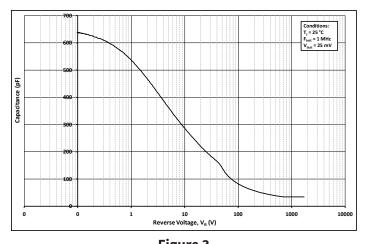
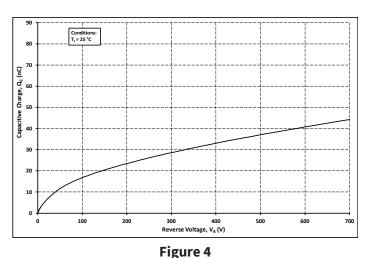
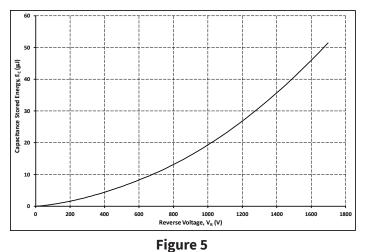


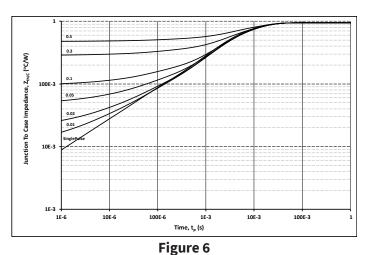
Figure 3Typical Capacitance vs Reverse Voltage



Typical Recovery Charge vs Reverse Voltage

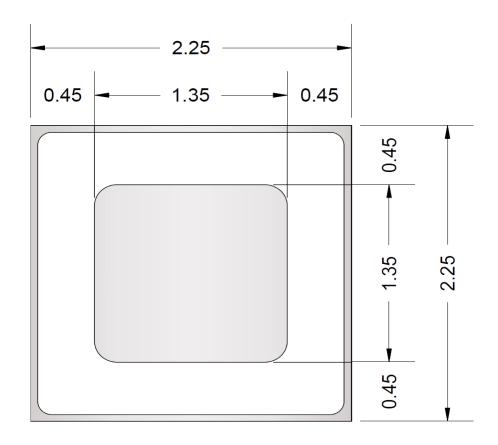


Typical Capacitance Stored Energy vs Reverse Voltage



Typical Thermal Impedance Characteristics

Product Dimensions CPW6-1700-Z005A (Package Type — Bare Die)



Product Ordering Information

Order Number	der Number Description Pac	
CPW6-1700-Z005A-FA6	Gen6 1700V 5A Schottky Diode, Full Wafer, Multiple Fab	Bare Die Product

Revision History

Revision History	Date of Change	Brief Summary
1	07/01/2022	Initial Release

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